



Main Features:

- Frequency Range: 7.9 to 8.4 GHz.
- Typical values: Psat 46 dBm, Gain 42 dB
- RF connectors (I/O): SMA Female
- TTL ON/OFF Control
- Power, current and temperature monitoring
- Compact aluminum housing
- Hi-reliability and dedicated screening/
environmental tests available under request

ERZ-HPA-0790-0840-46

The ERZ-HPA-0790-0840-46 is a High Power Amplifier providing an output power of 46 dBm and a gain of 43 dB. The compact size and modularity makes it ideal for a wide range of applications.

Typical applications:

- Industrial / Laboratory
- Satcom / Telecom
- Space / Aerospace / Military

Performance

Parameter	Value			Units
	Min	Typ	Max	
Frequency	7.9	-	8.4	GHz
Output Power (Psat) @CW	43	44	45	dBm
Output Power (Psat) @Pulsed	45	46	47	dBm
Small Signal Gain	38	42	46	dB
Gain Flatness	-	±1	-	dB
Switch ON/OFF Time	-	150/170	-	ns
VSWR input	-	-	1.5:1	-
VSWR output	-	-	1.5:1	-
DC Voltage	18	24	36	V
Power Consumption @Psat	-	200	230	W
Power Consumption @Disable mode	-	3	5	W
RF Connectors	SMA Female IN/OUT			-

Specifications at case temperature of 25°C

Output Power

Figure 1 shows saturated output power measurement as a function of frequency under pulsed conditions with a 100us pulse and 10% duty cycle at room temperature (25°C)

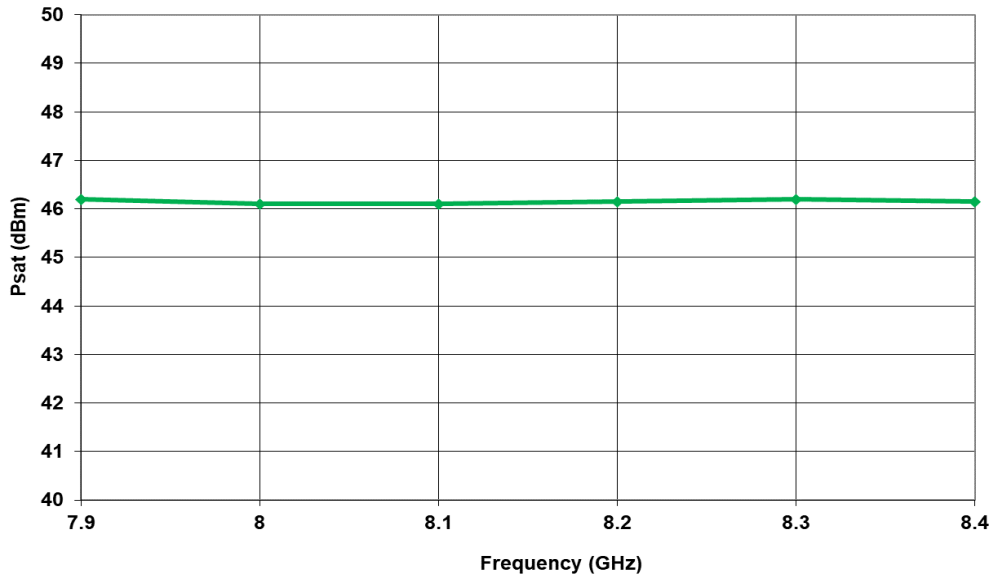


Figure 1: ERZ-HPA-0790-0840-46 Psat

Small Signal Gain

Figure 2 shows small signal gain measurement as a function of frequency at room temperature (25°C).

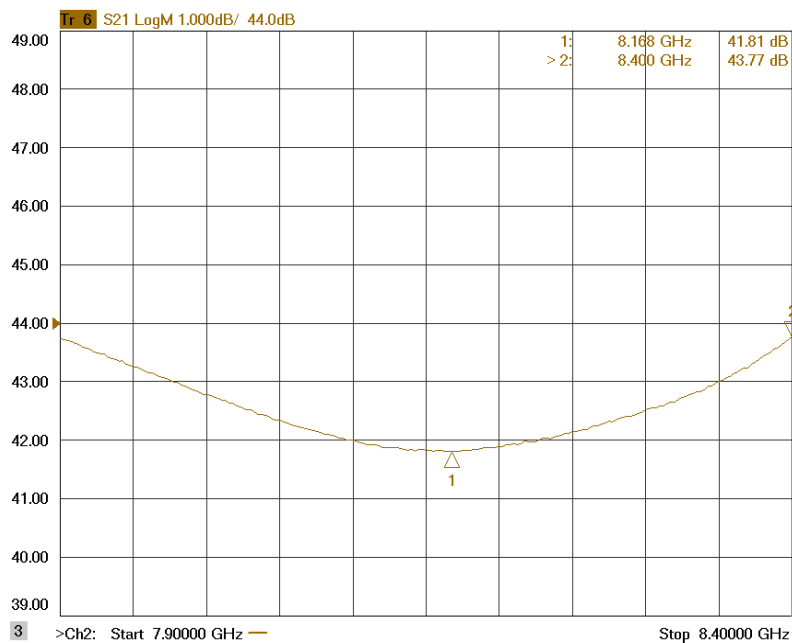


Figure 2: ERZ-HPA-0790-0840-46 Small Signal Gain

Input and Output Matching

Figure 3 and Figure 4 show input and output VSWR as a function of frequency at room temperature (25°C).

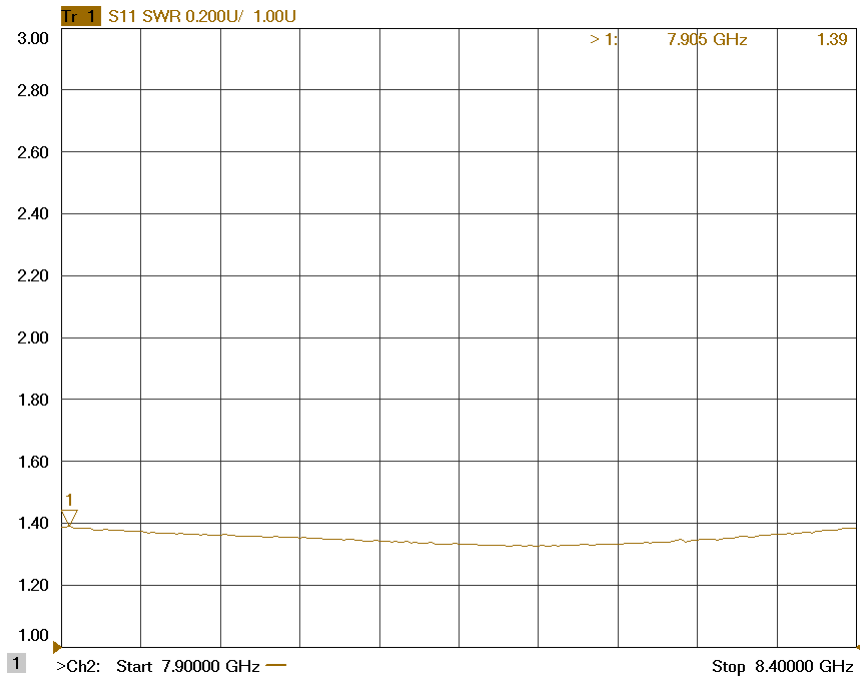


Figure 3: ERZ-HPA-0790-0840-46 Input Matching

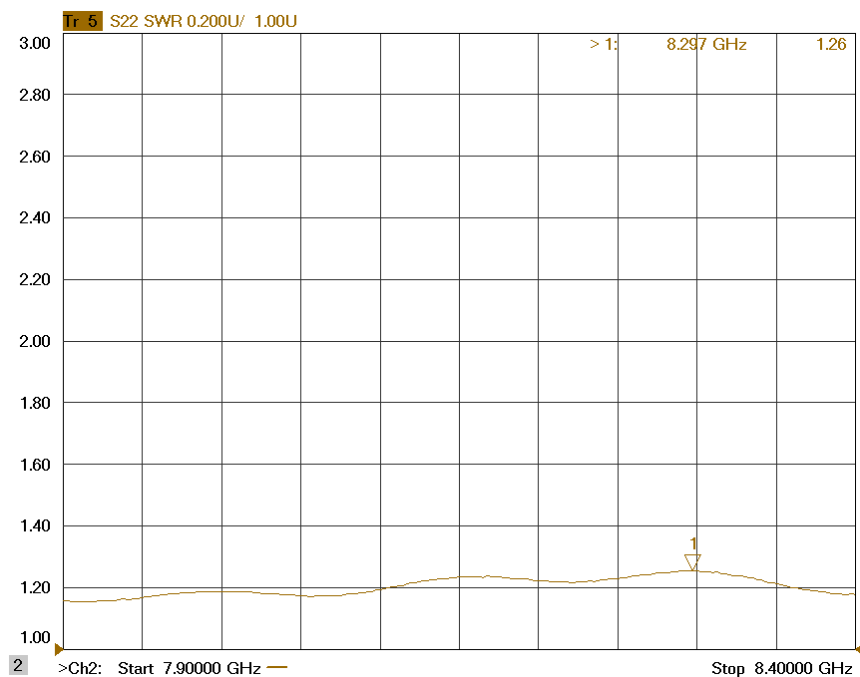


Figure 4: ERZ-HPA-0790-0840-46 Output Matching

Switch ON/OFF Time

Figure 5 and Figure 6 show switch ON/OFF time



Figure 5: ERZ-HPA-0790-0840-46 Switch ON Time

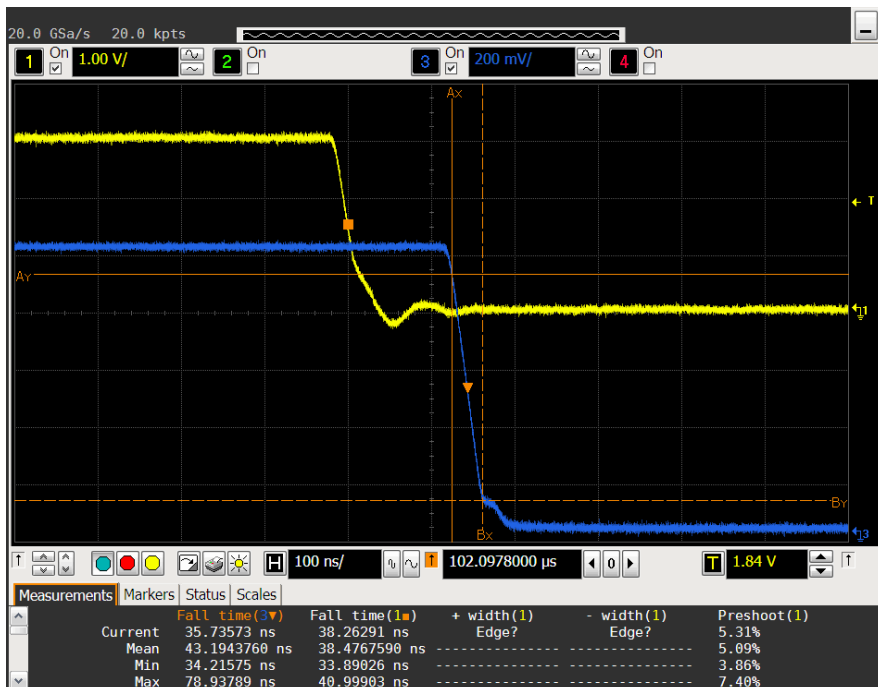


Figure 6: ERZ-HPA-0790-0840-46 Switch OFF Time

Output Power Detector

Figure 7 shows output power detector voltage versus output power at different frequencies.

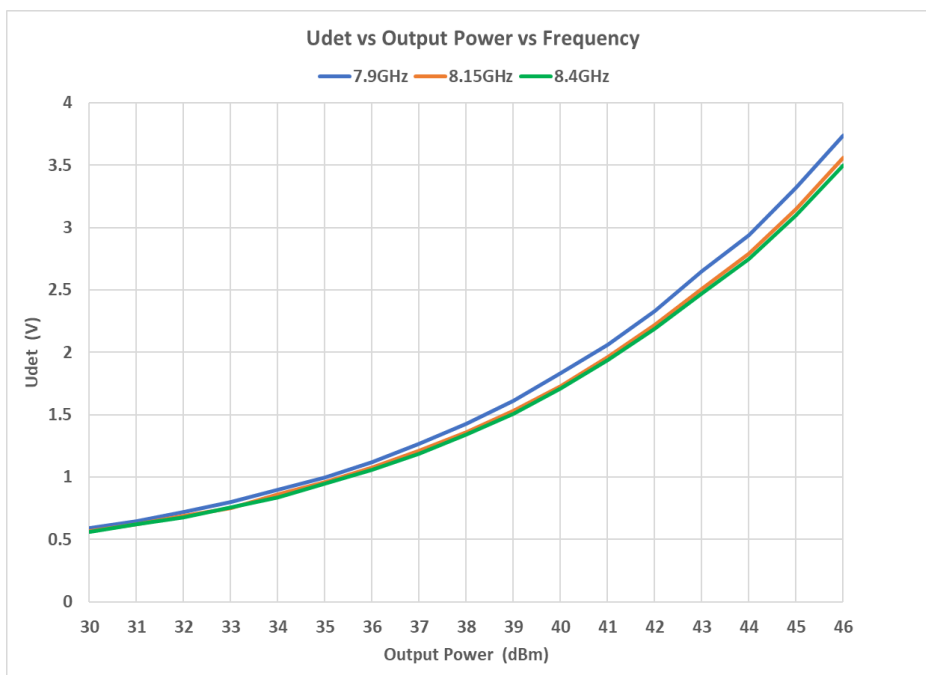
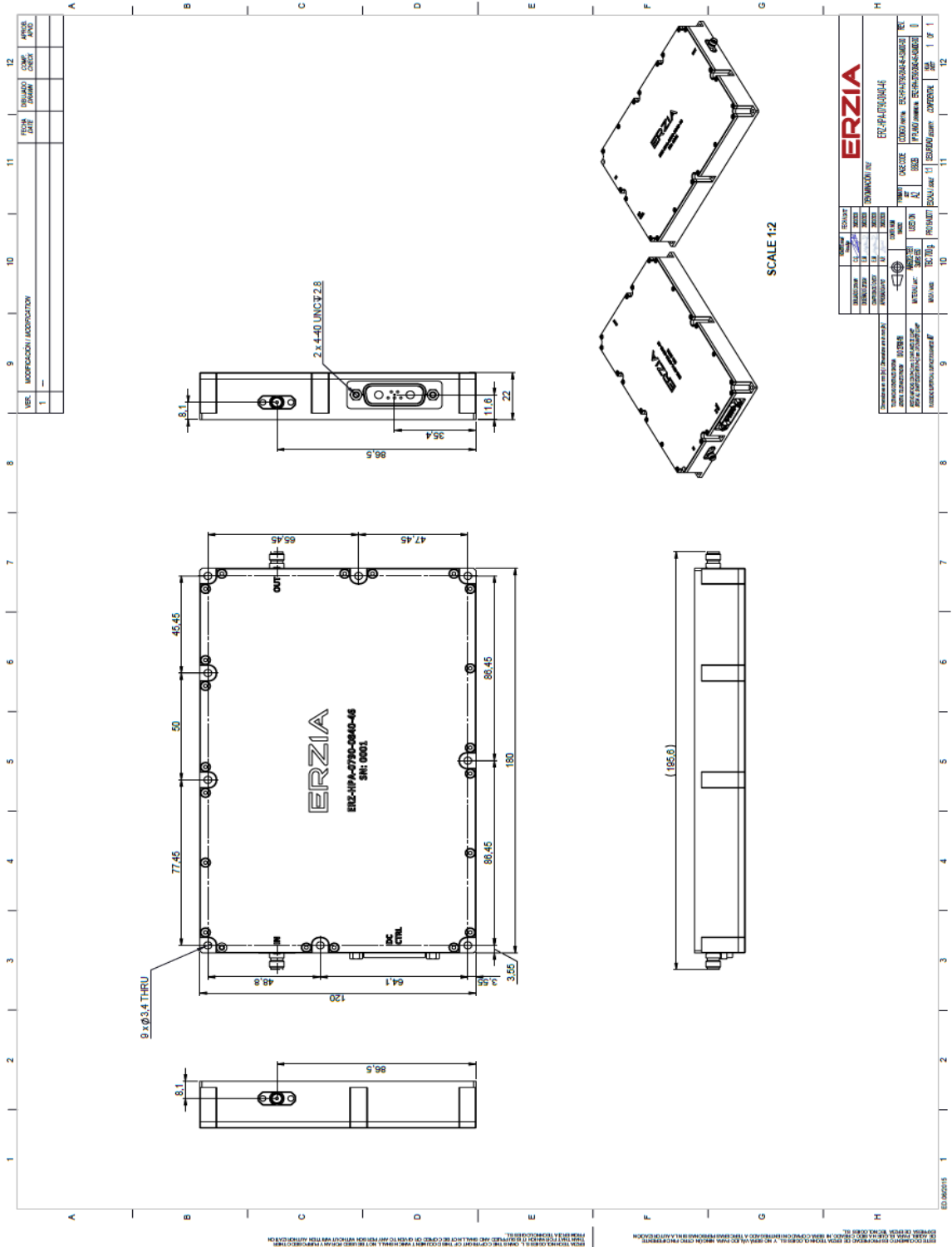


Figure 7: ERZ-HPA-0790-0840-46 Output power detector

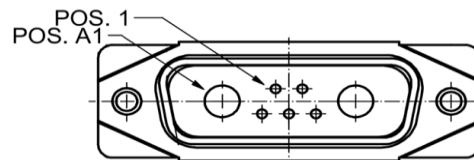
Figure 2: ERZ-HPA-0790-0840-46 Small Signal Gain

Mechanics and Housing



External Electrical Interface

- DC and Control: DSUB 7W2 Male type connector
- RF input and output: SMA Female



Pin No.	Label	Function	Description
A1	VDD	VDD	+(18...36) VDC
A2	PGND	Power Ground	Power Ground
1	EN	Enable	TTL Signal OFF (0V to 0.8V); ON (2V to 5.5V))
2	TEMP	Temperature Monitor	$V_o = -11.69 \text{ mV } C \times T + 1.8663 \text{ V}$
3	I_SEN	Current Sensor	$V_o = 0.1 \text{ V/A}$
4	DET	Output Power Detector	$V_o = 1.2 \text{ V @ } P_{out} = 37 \text{ dBm},$ $V_o = 1.75 \text{ V @ } P_{out} = 40 \text{ dBm},$ $V_o = 2.5 \text{ V @ } P_{out} = 43 \text{ dBm},$ $V_o = 3.6 \text{ V @ } P_{out} = 46 \text{ dBm}$
5	GND	Ground	Ground

Dimensions and Weight

- Dimensions: 180x120x22 mm
- Weight: 860 grams.

Absolute Maximum Ratings

Condition	Value
DC Voltage	+36 VDC
Maximum Input Power	+10 dBm @CW +20 dBm @Pulse conditions (pulse width: 100us, duty cycle: 10%)
Enable Control Voltage	+5.5 VDC
Operation temperature (at case)	-40 to 85 °C
Storage temperature	-55 to 125 °C

- Stress above these ratings may cause permanent damage to the device.
- It is final user responsibility to maintain the amplifier within the specified ranges.
- Note: Operation at +25°C with an output power in modulation or CW conditions higher than 44 dBm is not recommended. For an output power higher than 44 dBm the recommended operation is under pulse conditions (pulse width 100us and duty cycle 10%).

Measurements Conditions

All measurements provided in this report were performed at the following conditions:

Condition	Value
Temperature (DUT ON)	25 °C ± 1°C
Humidity	44% ± 10%
DUT Warm up time	30 min
DUT minimum operation time	24 hours
Test equipment warm up time	2 hours
Additional temperature cycles in climatic chamber (DUT OFF)	-40°C to 85°C

Environmental Specifications (By Design)

Operating Temperature:	-40 to +85 °C	(MIL-STD-810F, method 520.2)
Storage Temperature:	-55 to 125 °C	(MIL-STD-810F, method 520.2)
Vibration:	8g rms	(MIL-STD-810F, method 514.5)
Shock:	20g,11ms,saw-tooth	(MIL-STD-810F, method 516.5)
Acceleration:	15g	(MIL-STD-810F, method 513.5)

Documentation and Test Reports

All modules are at least delivered with: Electrical Test Report, Certificate of Conformance, Certificate of Acceptance and Origin. Optionally, units can be environmentally tested (temperature, vibration...).

Option (HS): Heat Sink

A heat sink (HS) can be provided to allow the operation of Power Amplifiers. Please note that most power amplifiers need heat sink or appropriate heat dissipation strategy.

Space / Military Usage

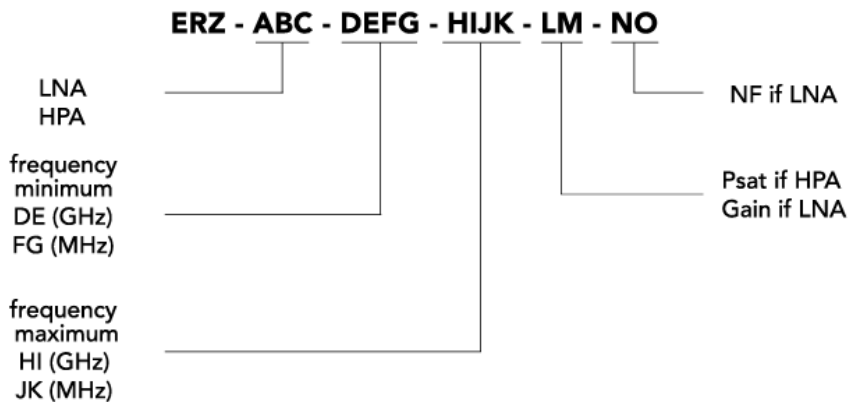
Most of ERZIA's products are based on rad-hard technologies and can be manufactured and integrated according to MIL / ECSS or specific hi-rel standard-screening for space, aeronautics, military or specific hi-reliability usage.

Customization and Extended Performances

ERZIA can fully design or adapt one of the existing RF amplifiers designs according to your specifications. Please contact us for additional information.

Model Number Codification

MODEL NUMBER



ERZIA

20160126_rev1.1

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